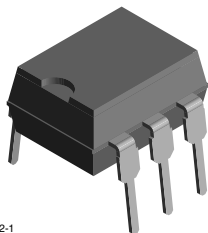
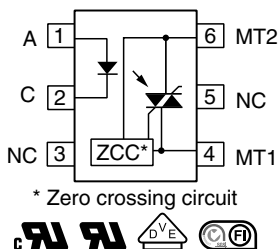


Optocoupler, Phototriac Output, Zero Crossing, High dV/dt, Low Input Current



21842-1



FEATURES

- High static dV/dt 5 kV/μs
- High input sensitivity $I_{FT} = 1.6$ mA, 2 mA, and 3 mA
- 300 mA on-state current
- Zero voltage crossing detector
- 700 V and 800 V blocking voltage
- Isolation rated voltage 4420 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

LINKS TO ADDITIONAL RESOURCES



3D Models



Design Tools



Related Documents



SPICE Models



Footprints



Schematics

DESCRIPTION

The VO4157 and VO4158 consists of a GaAs IRLED optically coupled to a photosensitive zero crossing TRIAC packaged in a DIP-6 package.

High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver resulting in an LED trigger current of 1.6 mA for bin D, 2 mA for bin H, and 3 mA for bin M.

The new phototriac zero crossing family uses a proprietary dV/dt clamp resulting in a static dV/dt of greater than 5 kV/μs.

The VO4157 and VO4158 isolates low-voltage logic from 120 V_{AC}, 240 V_{AC}, and 380 V_{AC} lines to control resistive, inductive, or capacitive loads including motors, solenoids, high current thyristors or TRIAC and relays.

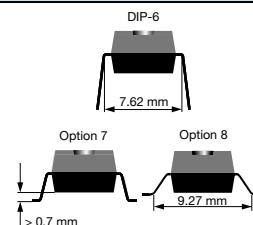
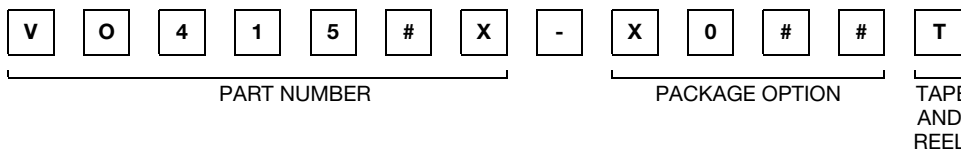
APPLICATIONS

- Solid-state relays
- Industrial controls
- Office equipment
- Consumer appliances

AGENCY APPROVALS

- [UL](#)
- [cUL](#)
- [DIN EN 60747-5-5 \(VDE 0884-5\)](#), available with option 1
- [FIMKO](#)

ORDERING INFORMATION



AGENCY CERTIFIED / PACKAGE	V _{DRM} 700	V _{DRM} 800		
	TRIGGER CURRENT, I _{FT} (mA)			
UL, cUL	1.6	1.6	2	3
DIP-6	VO4157D	VO4158D	VO4158H	-
SMD-6, option 7	-	-	VO4158H-X007T	VO4158M-X007T
SMD-6, option 9	-	VO4158D-X009T	-	-
VDE, UL, cUL	1.6	1.6	2	3
SMD-6, option 7	-	-	VO4158H-X017T	-
SMD-6, option 8	-	-	-	VO4158M-X018T

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Reverse voltage			V_R	6	V
Forward current			I_F	60	mA
Surge current			I_{FSM}	2.5	A
Derate from 25 °C				1.33	mW/°C
OUTPUT					
Peak off-state voltage		VO4157D/H/M	V_{DRM}	700	V
		VO4158D/H/M	V_{DRM}	800	V
RMS on-state current			I_{TM}	300	mA
Derate from 25 °C				6.6	mW/°C
COUPLER					
Storage temperature range			T_{stg}	-55 to +150	°C
Ambient temperature range			T_{amb}	-55 to +100	°C
Soldering temperature	Max. ≤ 10 s dip soldering ≥ 0.5 mm from case bottom		T_{sld}	260	°C

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
This phototriac should not be used to drive a load directly. It is intended to be a trigger device only

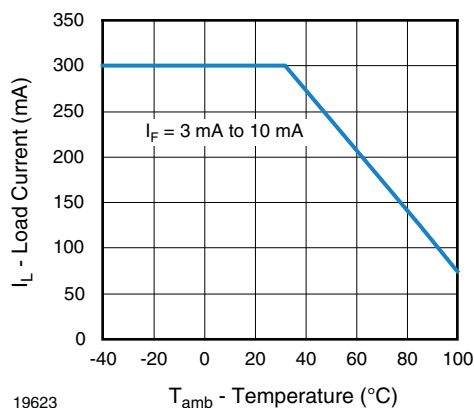
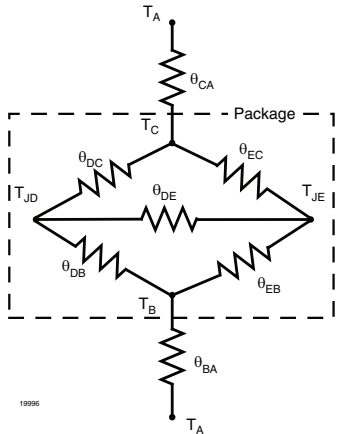


Fig. 1 - Recommended Operating Condition

THERMAL CHARACTERISTICS				
PARAMETER	SYMBOL	VALUE	UNIT	
LED power dissipation	P_{diss}	100	mW	
Output power dissipation	P_{diss}	500	mW	
Total power dissipation	P_{tot}	600	mW	
Maximum LED junction temperature	$T_{jmax.}$	125	°C	
Maximum output die junction temperature	$T_{jmax.}$	125	°C	
Thermal resistance, junction emitter to board	θ_{JEB}	150	°C/W	
Thermal resistance, junction emitter to case	θ_{JEC}	139	°C/W	
Thermal resistance, junction detector to board	θ_{JDB}	78	°C/W	
Thermal resistance, junction detector to case	θ_{JDC}	103	°C/W	
Thermal resistance, junction emitter to junction detector	θ_{JED}	496	°C/W	
Thermal resistance, case to ambient	θ_{CA}	3563	°C/W	

Note

- The thermal characteristics table above were measured at 25 °C and the thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 10\text{ mA}$		V_F	-	1.2	1.4	V
Reverse current	$V_R = 6\text{ V}$		I_R	-	0.1	10	μA
Input capacitance	$V_F = 0\text{ V}$, $f = 1\text{ MHz}$		C_i	-	25	-	pF
OUTPUT							
Repetitive peak off-state voltage	$I_{DRM} = 100\text{ μA}$	VO4157D/H/M	V_{DRM}	700	-	-	V
		VO4158D/H/M	V_{DRM}	800	-	-	V
Off-state current	$V_D = V_{DRM}$, $I_F = 0$		I_{DRM}	-	-	100	μA
On-state voltage	$I_T = 300\text{ mA}$		V_{TM}	-	-	3	V
On-state current	$PF = 1$, $V_{T(RMS)} = 1.7\text{ V}$		I_{TM}	-	-	300	mA
Off-state current in inhibit state	$I_F = 2\text{ mA}$, V_{DRM}		I_{DINH}	-	-	200	μA
Holding current			I_H	-	-	500	μA
Zero cross inhibit voltage	$I_F = \text{rated } I_{FT}$		V_{IH}	-	-	20	V
Critical rate of rise of off-state voltage	$V_D = 0.67 V_{DRM}$, $T_J = 25\text{ °C}$		dV/dt_{cr}	5000	-	-	V/μs
COUPLER							
LED trigger current, current required to latch output	$V_D = 3\text{ V}$	VO4157D	I_{FT}	-	-	1.6	mA
		VO4157H	I_{FT}	-	-	2	mA
		VO4157M	I_{FT}	-	-	3	mA
		VO4158D	I_{FT}	-	-	1.6	mA
		VO4158H	I_{FT}	-	-	2	mA
		VO4158M	I_{FT}	-	-	3	mA
Common mode coupling capacitance			C_{CM}	-	0.01	-	pF
Capacitance (input to output)	$f = 1\text{ MHz}$, $V_{IO} = 0\text{ V}$		C_{IO}	-	0.8	-	pF

Note

- Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements

SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	$t = 1 \text{ min}$	V_{ISO}	4420	V_{RMS}
Maximum transient isolation voltage		V_{IOTM}	8000	V_{peak}
Maximum repetitive peak isolation voltage		V_{IORM}	890	V_{peak}
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25^\circ\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500 \text{ V}, T_{amb} = 100^\circ\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Output safety power		P_{SO}	500	mW
Input safety current		I_{SI}	250	mA
Safety temperature		T_S	175	$^\circ\text{C}$
Creepage distance	Standard DIP-4		≥ 7	mm
Clearance distance	Standard DIP-4		≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits

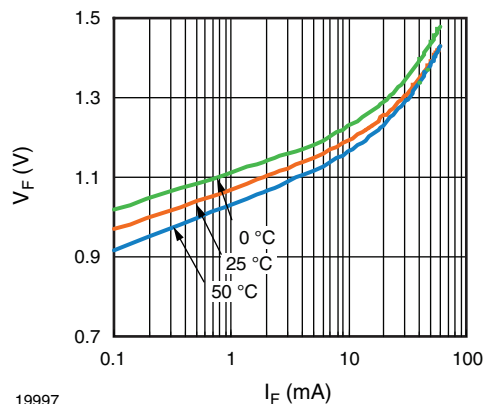
TYPICAL CHARACTERISTICS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)


Fig. 2 - Diode Forward Voltage vs. Forward Current

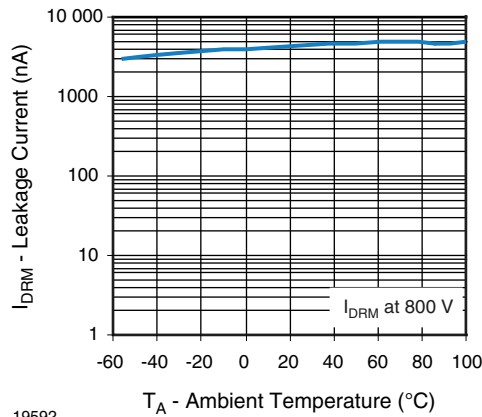


Fig. 4 - Leakage Current vs. Ambient Temperature

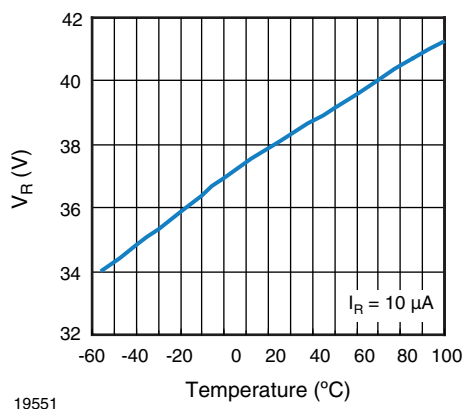


Fig. 3 - Diode Reverse Voltage vs. Temperature

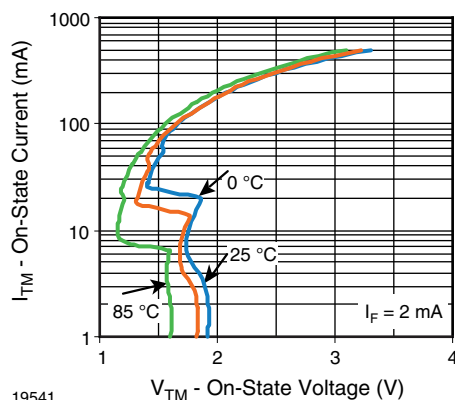
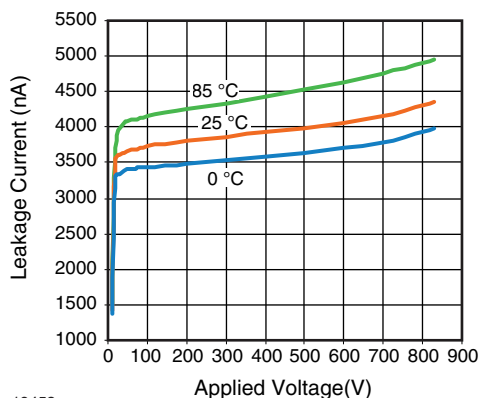
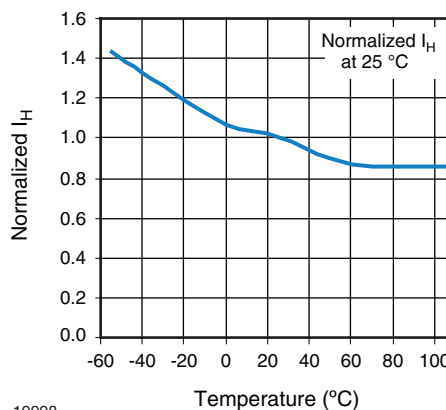


Fig. 5 - On State Current vs. On State Voltage



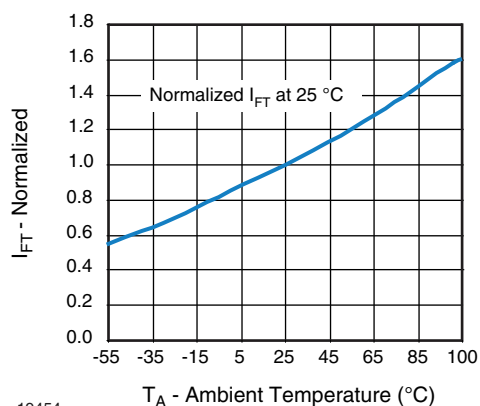
19453

Fig. 6 - Output Off Current (Leakage) vs. Voltage



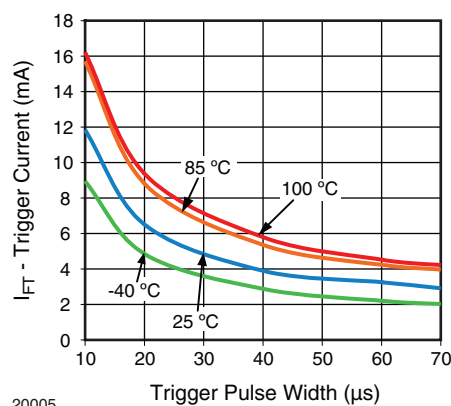
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Fig. 9 - Normalized Holding Current vs. Temperature

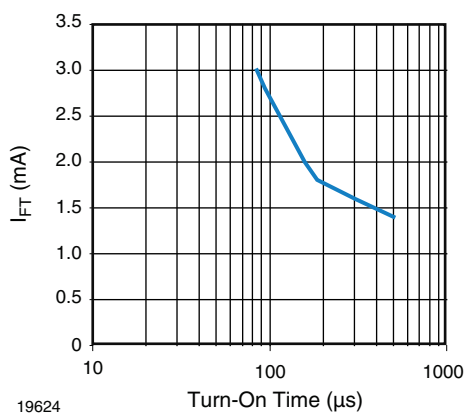


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Fig. 7 - Normalized Trigger Input Current vs. Temperature

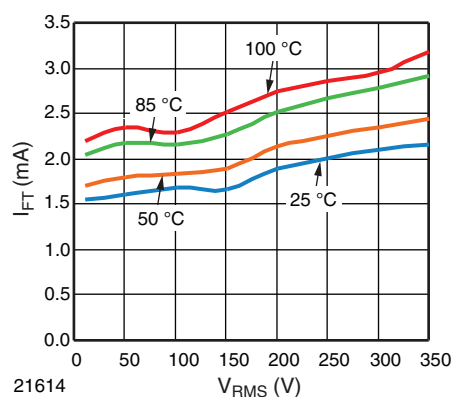


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Fig. 10 - I_{FT} vs. LED Pulse Width


19624

Fig. 8 - Trigger Current vs. Turn-On Time



21614

Fig. 11 - I_{FT} vs. V_{RMS} and Temperature

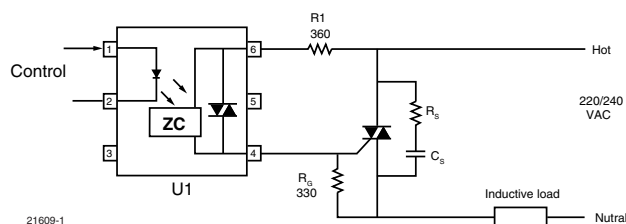


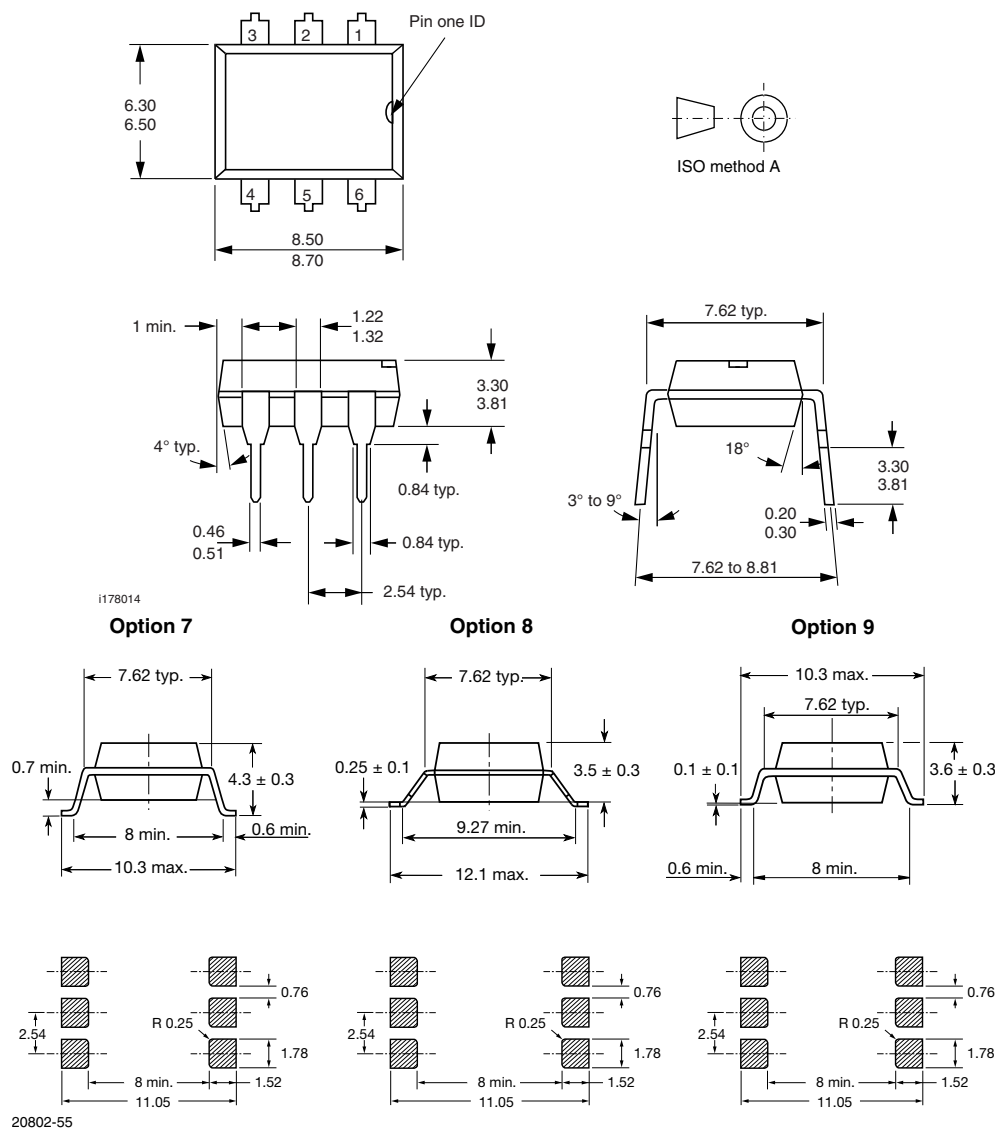
Fig. 12 - Basic Power Triac Driver Circuit

POWER FACTOR CONSIDERATIONS

As a zero voltage crossing optotriac, the commutating dV/dt spikes can inhibit one half of the TRIAC from turning on. If the spike potential exceeds the inhibit voltage of the zero-cross detection circuit, half of the TRIAC will be held-off and not turn-on. This hold-off condition can be eliminated by using a capacitor or RC snubber placed directly across the power triac as shown in fig. 11. Note that the value of the capacitor increases as a function of the load current.

The hold-off condition also can be eliminated by providing a higher level of LED drive current. The higher LED drive provides a larger photocurrent which causes the phototransistor to turn-on before the commutating spike has activated the zero-cross detection circuit. For example, if a device requires 1.5 mA for a resistive load, then 2.7 mA (1.8 times) may be required to control an inductive load whose power factor is less than 0.3.

PACKAGE DIMENSIONS in millimeters





PACKAGE MARKING (example)



Notes

- VDE logo is only marked on option 1 parts. Tape and reel suffix (T) is not part of the package marking



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